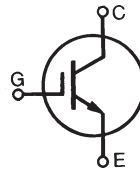


# High Voltage IGBT

**IXGH 10N170A**  
**IXGT 10N170A**

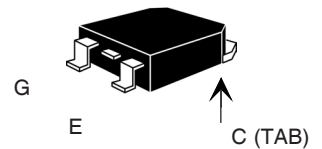
$V_{CES} = 1700 \text{ V}$   
 $I_{C25} = 10 \text{ A}$   
 $V_{CE(sat)} = 6.0 \text{ V}$   
 $t_{fi(typ)} = 35 \text{ ns}$

## Preliminary Data Sheet

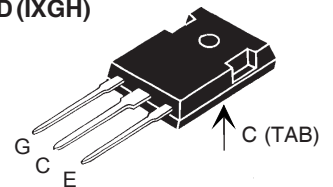


| Symbol  | Test Conditions   | Maximum Ratings                  |                  |
|---|---|----------------------------------|------------------|
| $V_{CES}$   | $T_J = 25^\circ\text{C to } 150^\circ\text{C}$  | 1700                             | V                |
| $V_{CGR}$   | $T_J = 25^\circ\text{C to } 150^\circ\text{C}; R_{GE} = 1 \text{ M}\Omega$                    | 1700                             | V                |
| $V_{GES}$   | Continuous  | $\pm 20$                         | V                |
| $V_{GEM}$   | Transient   | $\pm 30$                         | V                |
| $I_{C25}$   | $T_C = 25^\circ\text{C}$  | 10                               | A                |
| $I_{C90}$   | $T_C = 90^\circ\text{C}$  | 5                                | A                |
| $I_{CM}$  | $T_C = 25^\circ\text{C}, 1 \text{ ms}$  | 20                               | A                |
| <b>SSOA (RBSOA)</b>   | $V_{GE} = 15 \text{ V}, T_{VJ} = 125^\circ\text{C}, R_G = 22\Omega$<br>Clamped inductive load | $I_{CM} = 20$<br>@ $0.8 V_{CES}$ | A                |
| $t_{SC}$  | $T_J = 125^\circ\text{C}, V_{CE} = 1200 \text{ V}; V_{GE} = 15 \text{ V}, R_G = 22\Omega$     | 10                               | $\mu\text{s}$    |
| $P_C$   | $T_C = 25^\circ\text{C}$  | 140                              | W                |
| $T_J$   |   | -55 ... +150                     | $^\circ\text{C}$ |
| $T_{JM}$  |   | 150                              | $^\circ\text{C}$ |
| $T_{stg}$   |   | -55 ... +150                     | $^\circ\text{C}$ |
| $M_d$   | Mounting torque (M3) (TO-247)   | 1.13/10Nm/lb.in.                 |                  |
| Maximum lead temperature for soldering<br>1.6 mm (0.062 in.) from case for 10 s |   | 300                              | $^\circ\text{C}$ |
| <b>Weight</b>   |   | TO-247                           | 6 g              |
|   |   | TO-268                           | 4 g              |

### TO-268 (IXGT)



### TO-247 AD (IXGH)



G = Gate, C = Collector,  
E = Emitter, TAB = Collector

### Features

- International standard packages JEDEC TO-268 and JEDEC TO-247 AD
- High current handling capability
- Very high frequency
- MOS Gate turn-on - drive simplicity
- Rugged NPT structure
- Molding epoxies meet UL 94 V-0 flammability classification

### Applications

- Pulsar circuits
- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies

### Advantages

- High power density
- Suitable for surface mounting
- Easy to mount with 1 screw, (isolated mounting screw hole)

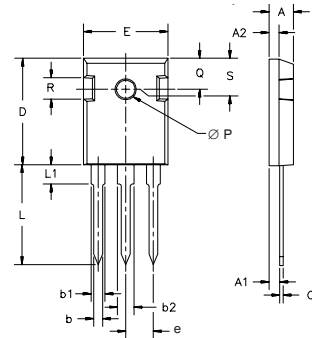
| Symbol        | Test Conditions  | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                      |
|---------------|--|---|------|----------------------|
|               |  | min.  | typ. | max.                 |
| $BV_{CES}$    | $I_C = 250 \mu\text{A}, V_{GE} = 0 \text{ V}$          | 1700  |      | V                    |
| $V_{GE(th)}$  | $I_C = 250 \mu\text{A}, V_{CE} = V_{GE}$               | 3.0   |      | V                    |
| $I_{CES}$     | $V_{CE} = 0.8 \cdot V_{CES}$<br>$V_{GE} = 0 \text{ V}$ | $T_J = 25^\circ\text{C}$  |      | 25 $\mu\text{A}$     |
|               |  | Note 1 $T_J = 125^\circ\text{C}$  |      | 500 $\mu\text{A}$    |
| $I_{GES}$     | $V_{CE} = 0 \text{ V}, V_{GE} = \pm 20 \text{ V}$      |   |      | $\pm 100 \text{ nA}$ |
| $V_{CE(sat)}$ | $I_C = I_{C90}, V_{GE} = 15 \text{ V}$                 | $T_J = 25^\circ\text{C}$  | 4.5  | 6.0 V                |
|               |  | $T_J = 125^\circ\text{C}$   | 5.2  | V                    |

| Symbol       | Test Conditions  | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |          |
|--------------|--|---|------|----------|
|              |  | min.  | typ. | max.     |
| $g_{fs}$     | $I_C = I_{C25}; V_{CE} = 20\text{ V}$<br>Note 2  | 3   | 5    | S        |
| $C_{ies}$    | $V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$  |   | 650  | pF       |
| $C_{oes}$    |  |   | 40   | pF       |
| $C_{res}$    |  |   | 22   | pF       |
| $Q_G$        | $I_C = I_{C90}; V_{GE} = 15\text{ V}, V_{CE} = 0.5 V_{CES}$  |   | 29   | nC       |
| $Q_{GE}$     |  |   | 5    | nC       |
| $Q_{GC}$     |  |   | 10   | nC       |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b><br>$I_C = I_{C25}, V_{GE} = 15\text{ V}$<br>$R_G = 22\ \Omega, V_{CE} = 0.5 V_{CES}$  |   | 46   | ns       |
| $t_{ri}$     |  |   | 57   | ns       |
| $t_{d(off)}$ |  |   | 190  | 360 ns   |
| $t_{fi}$     |  |   | 35   | ns       |
| $E_{off}$    |  |   | 0.38 | 0.8 mJ   |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 125^\circ\text{C}</math></b><br>$I_C = I_{C25}, V_{GE} = 15\text{ V}$<br>$R_G = 22\ \Omega, V_{CE} = 0.5 V_{CES}$ |   | 48   | ns       |
| $t_{ri}$     |  |   | 59   | ns       |
| $E_{on}$     |  |   | 1.2  | mJ       |
| $t_{d(off)}$ |  |   | 200  | ns       |
| $t_{fi}$     |  |   | 40   | ns       |
| $E_{off}$    |  | 0.6   | mJ   |          |
| $R_{thJC}$   | (TO-247)   |   |      | 0.89 K/W |
| $R_{thCK}$   |  |   | 0.25 | K/W      |

Notes: 1. Device must be heatsunk for high temperature leakage current measurements to avoid thermal runaway.

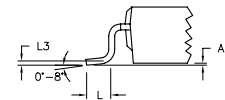
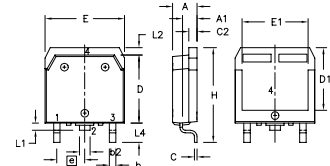
2. Pulse test,  $t \leq 300\ \mu\text{s}$ , duty cycle  $\leq 2\%$

### TO-247 AD Outline



| Dim.           | Millimeter |       | Inches |       |
|----------------|------------|-------|--------|-------|
|                | Min.       | Max.  | Min.   | Max.  |
| A              | 4.7        | 5.3   | .185   | .209  |
| A <sub>1</sub> | 2.2        | 2.54  | .087   | .102  |
| A <sub>2</sub> | 2.2        | 2.6   | .059   | .098  |
| b              | 1.0        | 1.4   | .040   | .055  |
| b <sub>1</sub> | 1.65       | 2.13  | .065   | .084  |
| b <sub>2</sub> | 2.87       | 3.12  | .113   | .123  |
| C              | .4         | .8    | .016   | .031  |
| D              | 20.80      | 21.46 | .819   | .845  |
| E              | 15.75      | 16.26 | .610   | .640  |
| e              | 5.20       | 5.72  | 0.205  | 0.225 |
| L              | 19.81      | 20.32 | .780   | .800  |
| L1             |            | 4.50  |        | .177  |
| ∅P             | 3.55       | 3.65  | .140   | .144  |
| Q              | 5.89       | 6.40  | 0.232  | 0.252 |
| R              | 4.32       | 5.49  | .170   | .216  |
| S              | 6.15       | BSC   | .242   | BSC   |

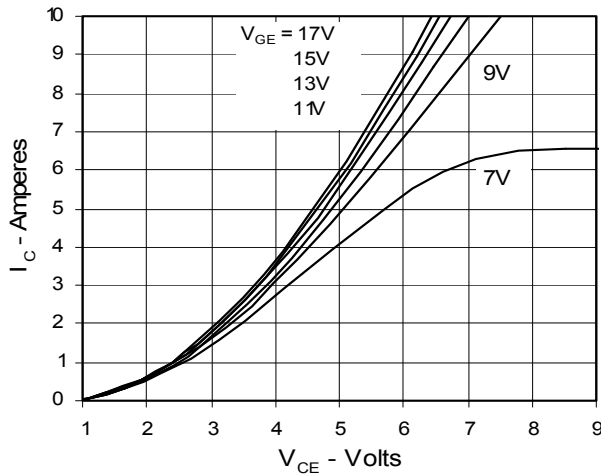
### TO-268 Outline



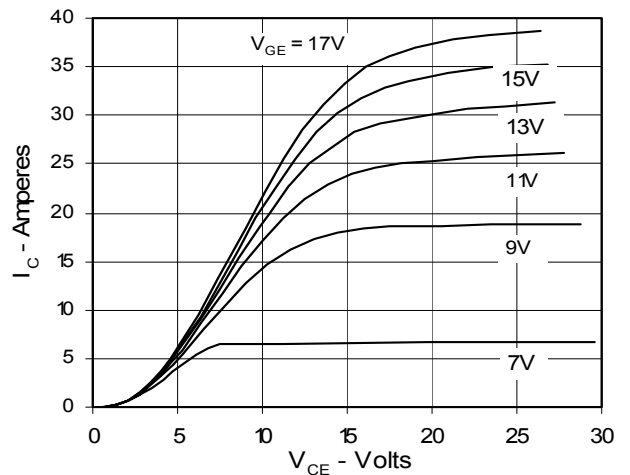
| Dim.           | Millimeter |       | Inches |      |
|----------------|------------|-------|--------|------|
|                | Min.       | Max.  | Min.   | Max. |
| A              | 4.9        | 5.1   | .193   | .201 |
| A <sub>1</sub> | 2.7        | 2.9   | .106   | .114 |
| A <sub>2</sub> | .02        | .25   | .001   | .010 |
| b              | 1.15       | 1.45  | .045   | .057 |
| b <sub>2</sub> | 1.9        | 2.1   | .75    | .83  |
| C              | .4         | .65   | .016   | .026 |
| D              | 13.80      | 14.00 | .543   | .551 |
| E              | 15.85      | 16.05 | .624   | .632 |
| E <sub>1</sub> | 13.3       | 13.6  | .524   | .535 |
| e              | 5.45       | BSC   | .215   | BSC  |
| H              | 18.70      | 19.10 | .736   | .752 |
| L              | 2.40       | 2.70  | .094   | .106 |
| L1             | 1.20       | 1.40  | .047   | .055 |
| L2             | 1.00       | 1.15  | .039   | .045 |
| L3             | 0.25       | BSC   | .010   | BSC  |
| L4             | 3.80       | 4.10  | .150   | .161 |

IXYS reserves the right to change limits, test conditions, and dimensions.

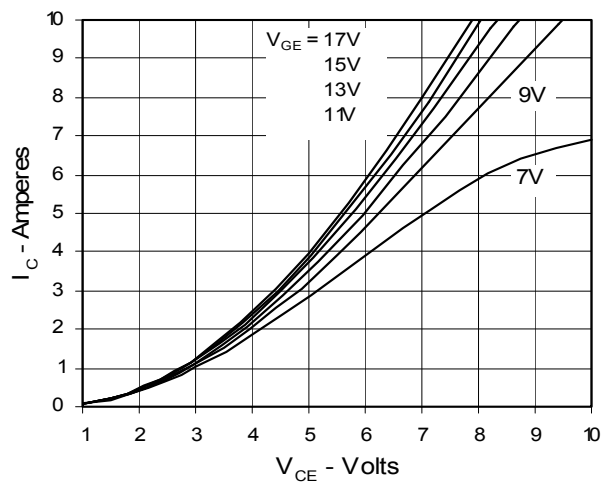
**Fig. 1. Output Characteristics**  
@ 25 Deg. C



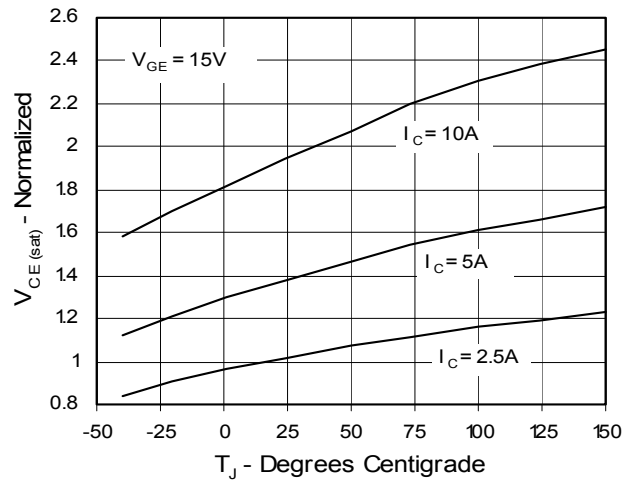
**Fig. 2. Extended Output Characteristics**  
@ 25 deg. C



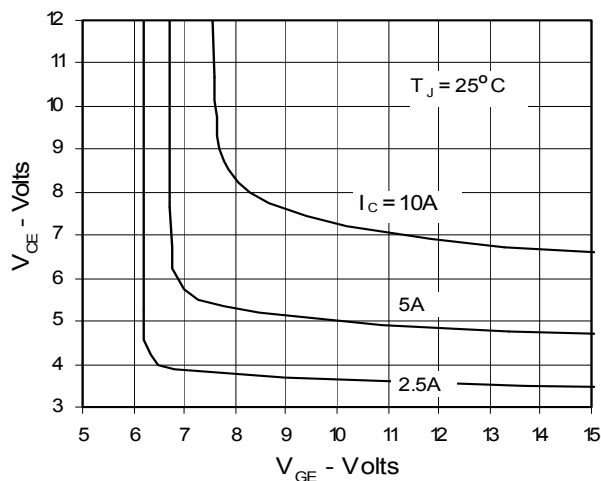
**Fig. 3. Output Characteristics**  
@ 125 Deg. C



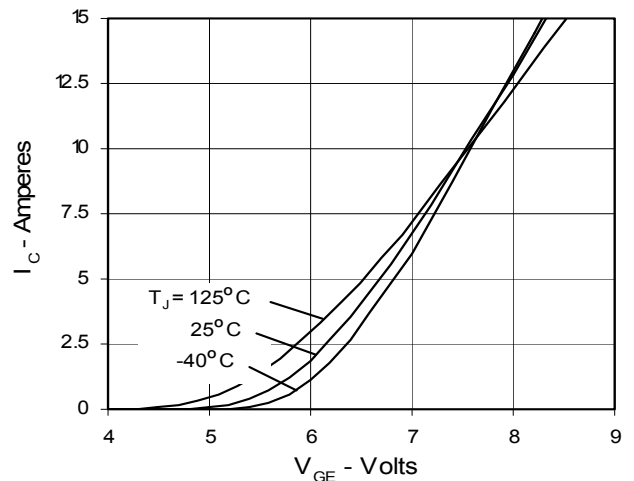
**Fig. 4. Temperature Dependence of  $V_{CE(sat)}$**



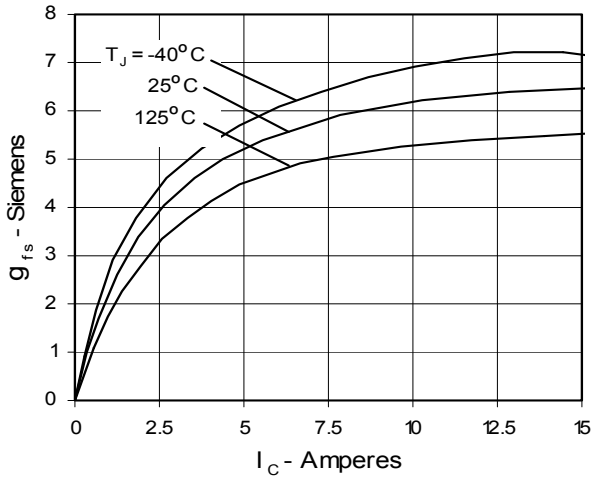
**Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter voltage**



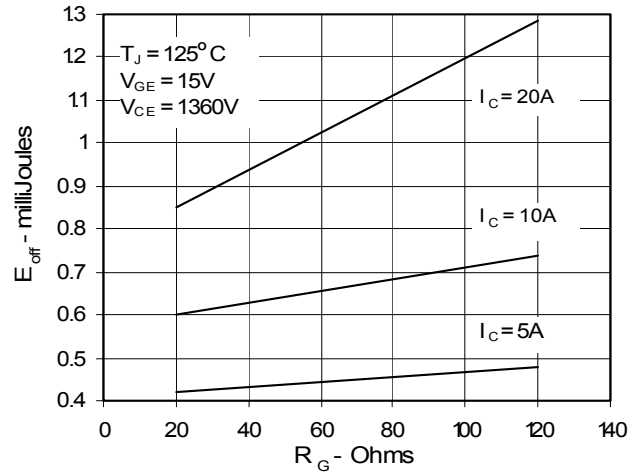
**Fig. 6. Input Admittance**



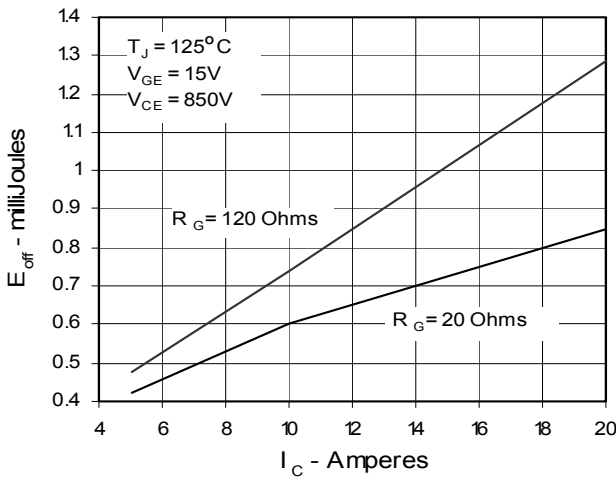
**Fig. 7. Transconductance**



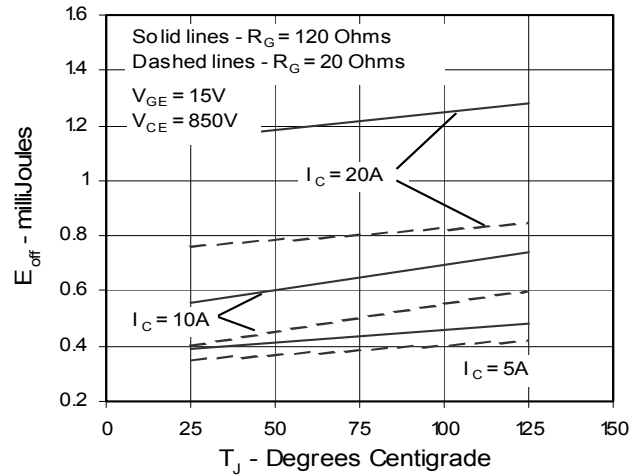
**Fig. 8. Dependence of  $E_{off}$  on  $R_G$**



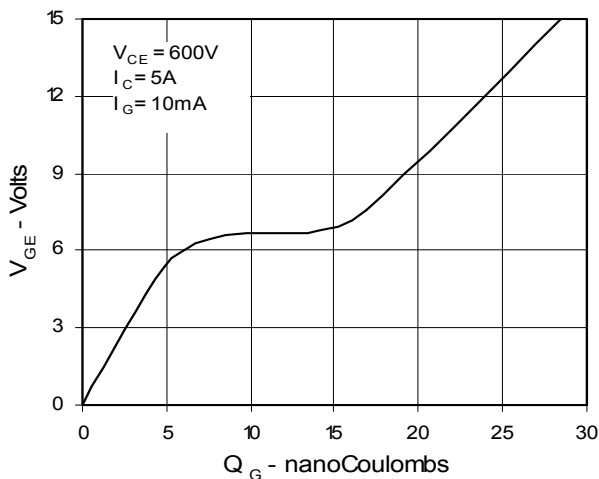
**Fig. 9. Dependence of  $E_{off}$  on  $I_C$**



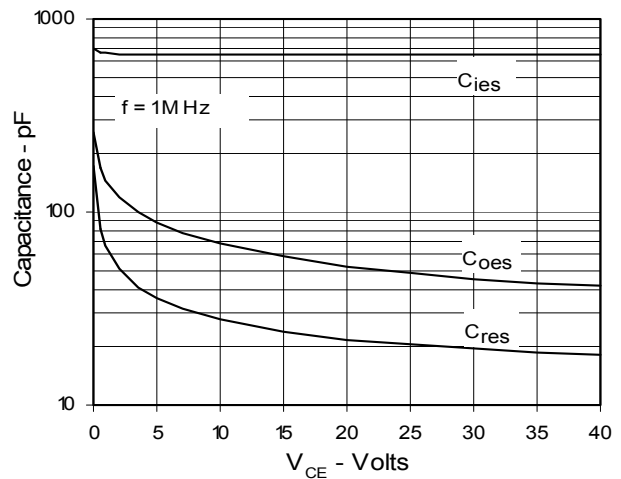
**Fig. 10. Dependence of  $E_{off}$  on Temperature**



**Fig. 11. Gate Charge**

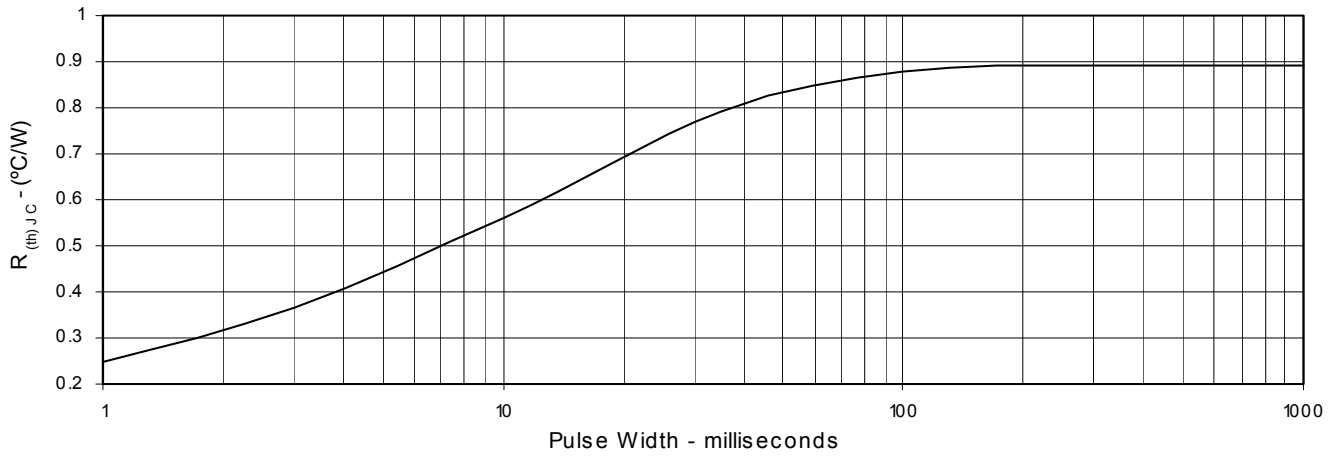


**Fig. 12. Capacitance**



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**Fig. 13. Maximum Transient Thermal Resistance**





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